

## BDW93/A/B/C

### Hammer Drivers, Audio Amplifiers Applications

Power Darlington TR

Complement to BDW94, BDW94A, BDW94B and BDW94C respectively



1.Base 2.Collector 3.Emitter

### **NPN Epitaxial Silicon Transistor**

Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
	: BDW93	45	V
	: BDW93A	60	V
	: BDW93B	80	V
	: BDW93C	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: BDW93	45	V
	: BDW93A	60	V
	: BDW93B	80	V
	: BDW93C	100	V
I <sub>C</sub>	Collector Current (DC)	12	А
I <sub>CP</sub>	*Collector Current (Pulse)	15	А
I <sub>B</sub>	Base Current	0.2	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	80	W
Tj	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

### Thermal Characteristics T<sub>C</sub>=25°C unless otherwise noted

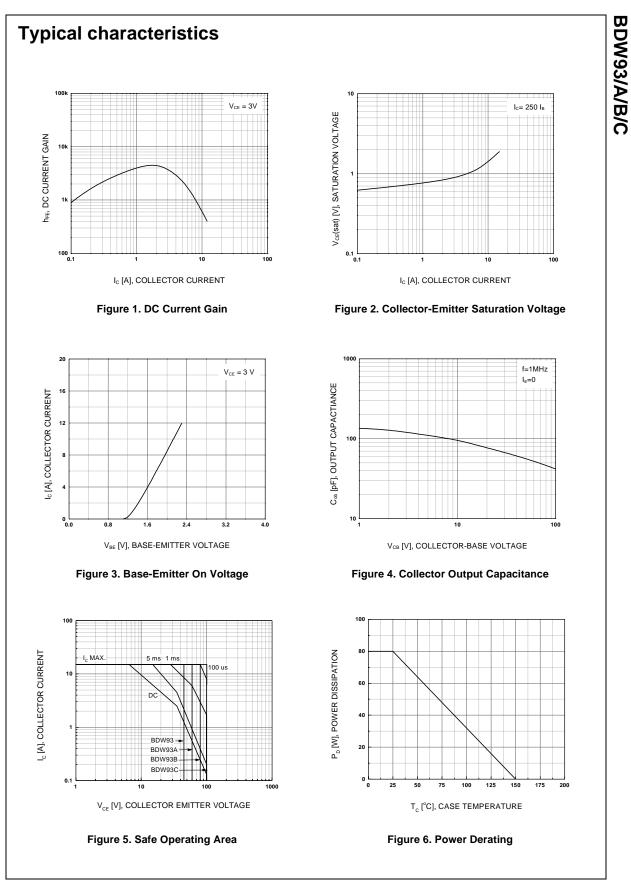
Symbol	Parameter		Value	Units
R <sub>θjc</sub>	Thermal Resistance	Junction to Case	1.5	°C/W

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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage					
0201	: BDW93	$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 0$	45			V
	: BDW93A		60			V
	: BDW93B		80			V
	: BDW93C		100			V
СВО	Collector Cut-off Current					
020	: BDW93	$V_{CB} = 45V, I_E = 0$			100	μA
	: BDW93A	$V_{CB} = 60V, I_E = 0$			100	μA
	: BDW93B	$V_{CB} = 80V, I_{E} = 0$			100	μA
	: BDW93C	$V_{CB} = 100V, I_E = 0$			100	μA
CEO	Collector Cut-off Current					
	: BDW93	$V_{CE} = 45V, I_{B} = 0$			1	mA
	: BDW93A	$V_{CE} = 60V, I_{B} = 0$			1	mA
	: BDW93B	$V_{CE} = 80V, I_{B} = 0$			1	mA
	: BDW93C	$V_{CE} = 100V, I_{B} = 0$			1	mA
EBO	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			2	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = 3V, I_{C} = 3A$	1000			
		$V_{CE} = 3V, I_{C} = 5A$	750		20000	
		$V_{CE} = 3V, I_{C} = 10A$	100			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A, I <sub>B</sub> = 20mA			2	V
		$I_{\rm C} = 10$ A, $I_{\rm B} = 100$ mA			3	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> = 5A, I <sub>B</sub> = 20mA			2.5	V
		I <sub>C</sub> = 10A, I <sub>B</sub> = 100mA			4	V
V <sub>F</sub>	* Parallel Diode Forward Voltage	I <sub>F</sub> = 5A		1.3	2	V
	5	$I_{\rm F} = 10A$		1.8	4	V

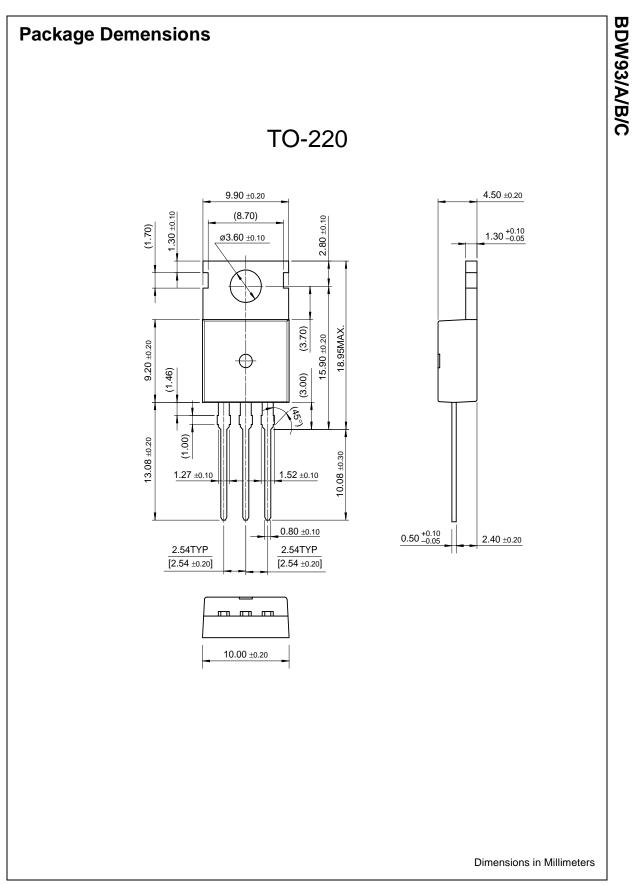
\* Pulse Test: PW=300µs, duty Cycle =1.5% Pulsed

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